## NSN 5962-01-424-3336

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-424-3336 **Body Length:** 1.700 inches **Body Width:** Between 0.350 inches and 0.405 inches **Body Height:** 0.232 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Monolithic and electrostatic sensitive and low power and burn in, mil-std-883, class b **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Terminal Surface Treatment:** Solder **Product Name:** Microcircuit, memory, digital, cmos, 128k x 8 static random access memory (sram) low power **Voltage Rating And Type Per Characteristic:** -0.5 volts input and 7.0 volts input **Time Rating Per Chacteristic:** 20.00 nanoseconds access **Memory Device Type:** Ram **Special Features:** Dual ce **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 32 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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